## NSN 5962-01-130-8656

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Body Length:
Between 1.060 inches and 1.120 inches
Body Width:
Between 0.370 inches and 0.400 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Data link 76301
Features Provided:
Hermetically sealed and electrostatic sensitive and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.3 volts power source
Time Rating Per Chacteristic:
650.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Ram
Test Data Document:
13499-351-8489 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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